

N-Channel 60 V (D-S) 175 °C MOSFET

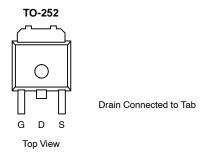
PRODUCT SUMMARY			
V _{DS} (V)	$r_{DS(on)}(\Omega)$	I _D (A)	
60	0.065 @ V _{GS} = 10 V	15	
	0.090 @ V _{GS} = 4.5 V	14	

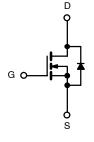
FEATURES



- TrenchFET® Power MOSFET
- 175°C Maximum Junction Temperature

Available





N-Channel MOSFET

Ordering Information: SUD15N06-90L SUD15N06-90L—E3 (Lead (Pb)-Free)

ABSOLUTE MAXIMUM RATINGS (T _C = 25°C UNLESS OTHERWISE NOTED)					
Parameter		Symbol	Limit	Unit	
Gate-Source Voltage		V _{GS}	±20	V	
Continuous Drain Current (T _J = 175°C)	T _C = 25°C		15		
	T _C = 100°C	I _D	12		
Pulsed Drain Current		I _{DM}	30	Α	
Continuous Source Current (Diode Conduction)		IS	15		
Avalanche Current		I _{AR}	15		
Repetitive Avalanche Energy (Duty Cycle ≤ 1%)	L = 0.1 mH	E _{AR}	11	mJ	
Maximum Power Dissipation	T _C = 25°C		37	144	
	T _A = 25°C	P _D	2ª	w	
Operating Junction and Storage Temperature Range		T _J , T _{stg}	-55 to 175	°C	

THERMAL RESISTANCE RATINGS				
Parameter	Symbol	Typical	Maximum	Unit
Junction-to-Ambient Free Air, FR4 Board Mount ^a	R _{thJA}	60	70	
Junction-to-Case	R _{thJC}	3.3	4.0	°C/W

1.36 x 2.1 surface mounted on 1" x 1" FR4 Board.

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Parameter	Symbol	Test Condition	Min	Typ ^a	Max	Unit	
Static			•		•	•	
Drain-Source Breakdown Voltage	V _{(BR)DSS}	$V_{GS} = 0 \text{ V}, I_D = 250 \mu A$	60				
Gate Threshold Voltage	V _{GS(th)}	$V_{DS} = V_{GS}$, $I_D = 250 \mu A$	1.0	2.0	3.0	V	
Gate-Body Leakage	I _{GSS}	V_{DS} = 0 V, V_{GS} = ± 20 V			±100	nA	
Zero Gate Voltage Drain Current		$V_{DS} = 60 \text{ V}, V_{GS} = 0 \text{ V}$			1		
	I _{DSS}	$V_{DS} = 60 \text{ V}, V_{GS} = 0 \text{ V}, T_{J} = 125^{\circ}\text{C}$			50	μΑ	
		$V_{DS} = 60 \text{ V}, V_{GS} = 0 \text{ V}, T_{J} = 175^{\circ}\text{C}$			150	1	
On-State Drain Current ^b	I _{D(on)}	V _{DS} = 5 V, V _{GS} = 10 V	15			Α	
		$V_{GS} = 10 \ V, I_D = 10 \ A$		0.050	0.065		
		$V_{GS} = 10 \text{ V}, I_D = 10 \text{ A}, T_J = 125 ^{\circ}\text{C}$			0.12	Ω	
Drain-Source On-State Resistance ^b	r _{DS(on)}	V _{GS} = 10 V, I _D = 10 A, T _J = 175°C			0.15		
		$V_{GS} = 4.5 \text{ V}, I_D = 5 \text{ A}$		0.065	0.090		
Forward Transconductanceb	9fs	V _{DS} = 15 V, I _D = 10 A		11		S	
Dynamic			· ·	I	l .		
Input Capacitance	C _{iss}			524			
Output Capacitance	C _{oss}	$V_{GS} = 0 \text{ V}, V_{DS} = 25 \text{ V}, f = 1 \text{ MHz}$		98		pF	
Reverse Transfer Capacitance	C _{rss}			28			
Total Gate Charge ^c	Qg			12	20	nC	
Gate-Source Charge ^c	Q _{gs}	$V_{DS} = 30 \text{ V}, \ V_{GS} = 10 \text{ V}, \ I_D = 15 \text{ A}$		2			
Gate-Drain Charge ^c	Q _{gd}			3.5			
Turn-On Delay Time ^c	t _{d(on)}			7	20	ns	
Rise Time ^c	t _r	Von = 30 V Br = 2 O		8	25		
Turn-Off Delay Time ^c	t _{d(off)}	$V_{DD} = 30 \text{ V, } R_L = 2 \Omega$ $I_D \cong 15 \text{ A, } V_{GEN} = 10 \text{ V, } R_g = 2.5 \Omega$		15	40		
Fall Time ^c	t _f			7	20		
Source-Drain Diode Ratings ar	nd Characteristi	cs (T _C = 25°C)	•	1	ı		
Pulsed Current	I _{SM}				30	А	
Diode Forward Voltage	V _{SD}	I _F = 15 A, V _{GS} = 0 V		0.9	1.2	V	
Reverse Recovery Time	t _{rr}	I _F = 15 A, di/dt = 100 A/μs		29	60	ns	

- For design aid only; not subject to production testing. Pulse test; pulse width $\leq 300~\mu s$, duty cycle $\leq 2\%$. Independent of operating temperature.

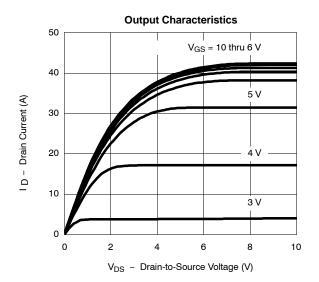
Stresses beyond those listed under "Absolute Maximum Ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated in the operational sections of the specifications is not implied. Exposure to absolute maximum rating conditions for extended periods may affect device reliability.

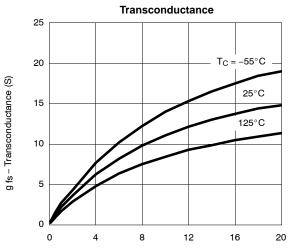
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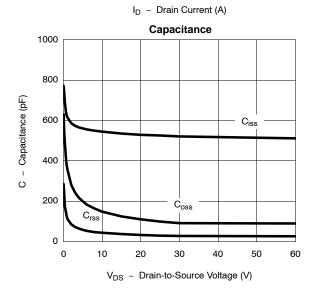


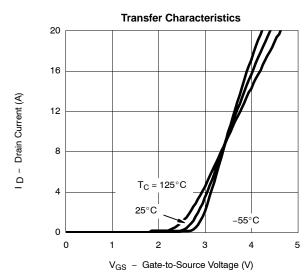
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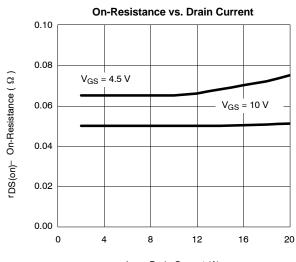
TYPICAL CHARACTERISTICS (25°C UNLESS NOTED)

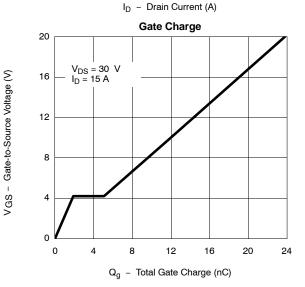






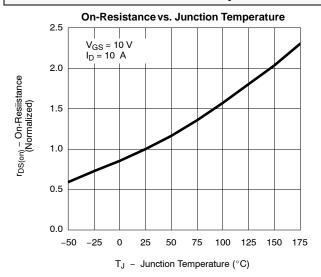


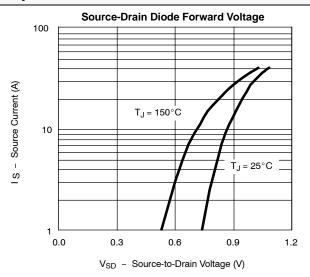




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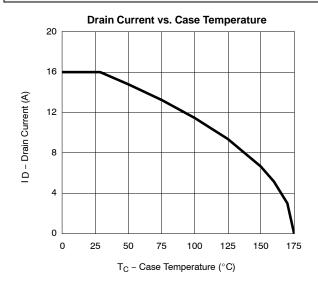


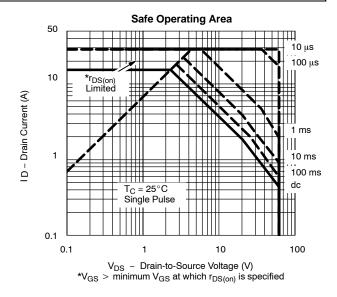


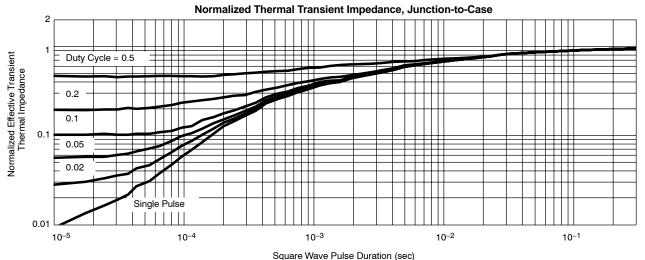
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THERMAL RATINGS







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